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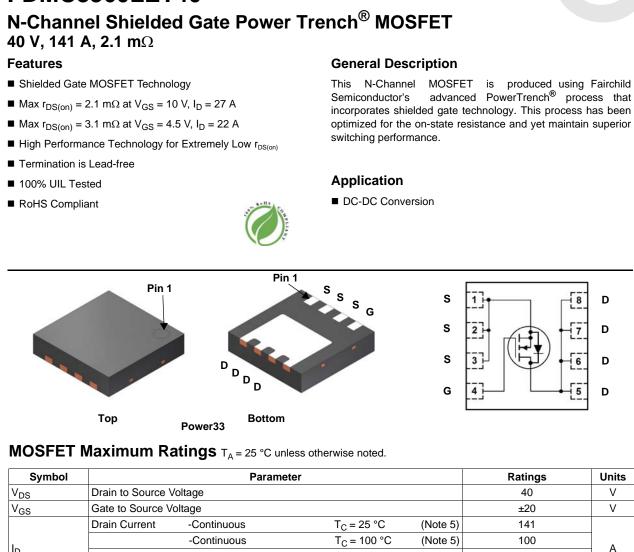


## **ON Semiconductor**®

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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (\_), the underscore (\_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (\_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at <a href="mailto:www.onsemi.com">www.onsemi.com</a>. Please email any questions regarding the system integration to <a href="mailto:Fairchild\_questions@onsemi.com">Fairchild\_questions@onsemi.com</a>.

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۷GS	Gale to Source vo	maye			±20	v
	Drain Current	-Continuous	T <sub>C</sub> = 25 °C	(Note 5)	141	
		-Continuous	T <sub>C</sub> = 100 °C	(Note 5)	100	^
D	-Continuous		T <sub>A</sub> = 25 °C	(Note 1a)	27	— A
		-Pulsed		(Note 4)	658	
E <sub>AS</sub>	Single Pulse Avala	anche Energy		(Note 3)	253	mJ
P <sub>D</sub>	Power Dissipation Power Dissipation		T <sub>C</sub> = 25 °C		75	w
			T <sub>A</sub> = 25 °C	(Note 1a)	2.8	vv
T <sub>J</sub> , T <sub>STG</sub>	Operating and Sto	rage Junction Tempera	ture Range		-55 to +175	°C

### **Thermal Characteristics**

$R_{\theta JC}$	Thermal Resistance, Junction to Case	(Note 1)	2.0	°C/W
$R_{\thetaJA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	53	0/10

#### **Package Marking and Ordering Information**

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMC8360LET	FDMC8360LET40	Power33	13 "	12 mm	3000 units

1



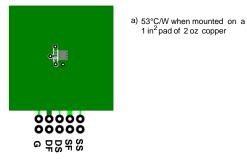
September 2015

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
Off Chara	acteristics					
BV <sub>DSS</sub>	Drain to Source Breakdown Voltage	$I_{D} = 250 \ \mu A, \ V_{GS} = 0 \ V$	40			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		20		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = 32 V, V_{GS} = 0 V$			1	μA
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA
On Chara	octeristics					
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \ \mu A$	1.0	1.7	3.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		-6		mV/°C
r <sub>DS(on)</sub>		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 27 A		1.4	2.1	
	Static Drain to Source On Resistance	$V_{GS} = 4.5 \text{ V}, I_D = 22 \text{ A}$		2.1	3.1	mΩ
		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 27 A, T <sub>J</sub> = 150 °C		2.3	3.5	
9 <sub>FS</sub>	Forward Transconductance	$V_{DD} = 5 \text{ V}, \ I_D = 27 \text{ A}$		138		S
Dynamic	Characteristics					
C <sub>iss</sub>	Input Capacitance			3785	5300	pF
C <sub>oss</sub>	Output Capacitance	V <sub>DS</sub> = 20 V, V <sub>GS</sub> = 0 V, f = 1 MHz		1220	1710	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			57	80	pF
R <sub>g</sub>	Gate Resistance		0.1	0.8	1.6	Ω
Switching	g Characteristics					
t <sub>d(on)</sub>	Turn-On Delay Time			14	26	ns
t <sub>r</sub>	Rise Time	$V_{DD} = 20 \text{ V}, I_D = 27 \text{ A},$		8	16	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{GS} = 10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		35	57	ns
t <sub>f</sub>	Fall Time			7	14	ns
Q <sub>g(TOT)</sub>	Total Gate Charge	$V_{GS} = 0 V$ to 10 V		57	80	nC
Q <sub>g(TOT)</sub>	Total Gate Charge	$V_{GS} = 0 \text{ V to } 4.5 \text{ V} \text{ V}_{DD} = 20 \text{ V},$		27	38	nC
Q <sub>gs</sub>	Gate to Source Charge	I <sub>D</sub> = 27 A		9.9		nC
Q <sub>gd</sub>	Gate to Drain "Miller" Charge			8.1		nC

V <sub>SD</sub>	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_{S} = 27 A$	(Note 2)	0.8	1.3	V
		$V_{GS} = 0 V, I_{S} = 1.9 A$	(Note 2)	0.7	1.2	V
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 27 A, di/dt = 100 A/μs		47	76	ns
Q <sub>rr</sub>	Reverse Recovery Charge			30	48	nC

Notes:

1. R<sub>0,A</sub> is determined with the device mounted on a 1 in<sup>2</sup> pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R<sub>0,JC</sub> is guaranteed by design while R<sub>0CA</sub> is determined by the user's board design.



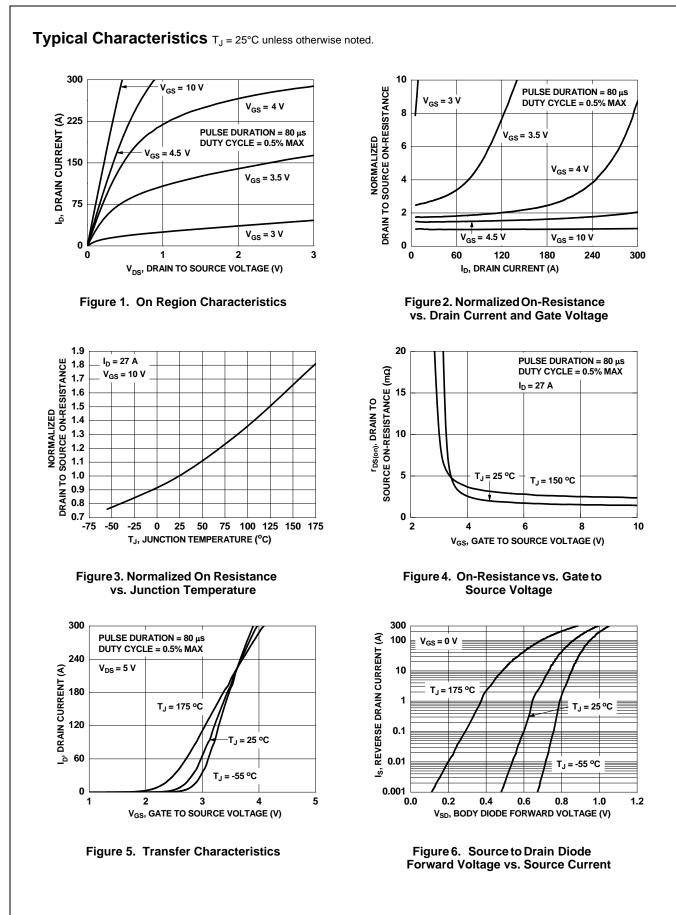
b) 125°C/W when mounted on a minimum pad

2. Pulse Test: Pulse Width < 300  $\mu$ s, Duty cycle < 2.0%. 3. E<sub>AS</sub> of 253 mJ is based on starting T<sub>J</sub> = 25 °C, L = 3 mH, I<sub>AS</sub> = 13 A, V<sub>DD</sub> = 40 V, V<sub>GS</sub> = 10 V. 100% test at L = 0.1 mH, I<sub>AS</sub> = 42 A.

4. Pulsed Id please refer to Fig 11 SOA graph for more details.

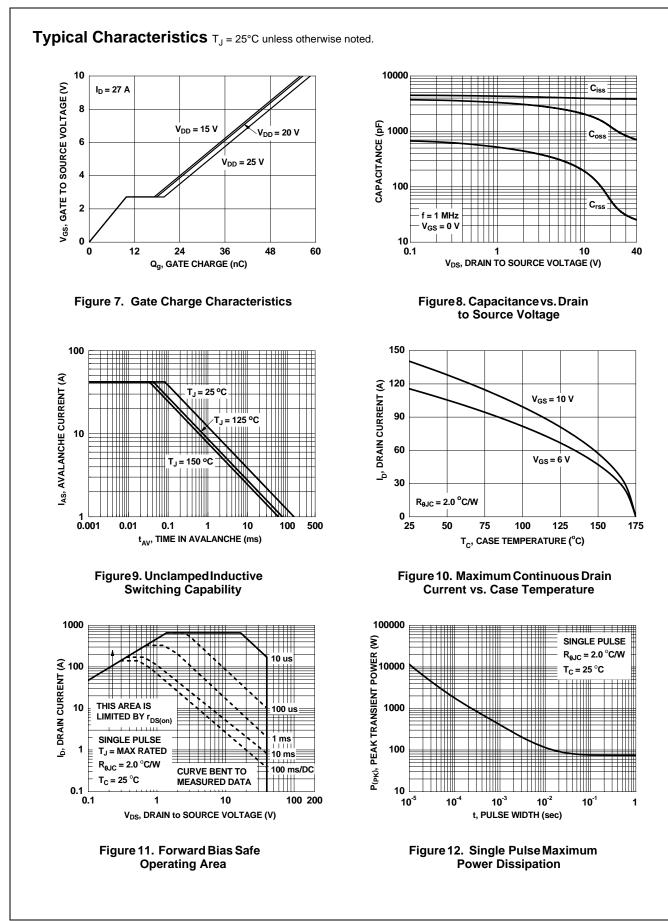
5. Computed continuous current limited to Max Junction Temperature only, actual continuous current will be limited by thermal & electro-mechanical application board design.

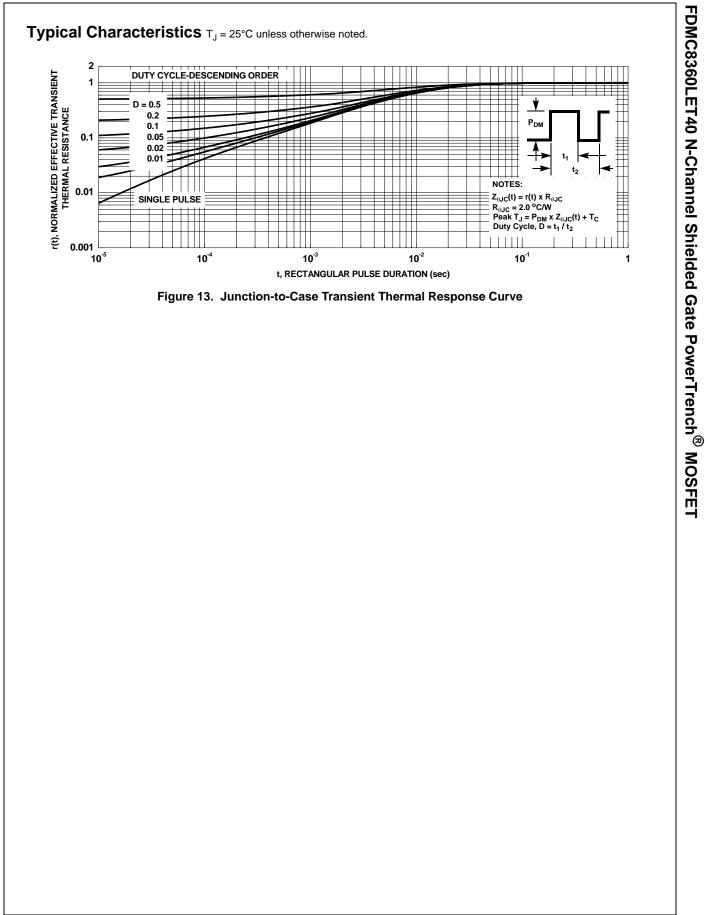
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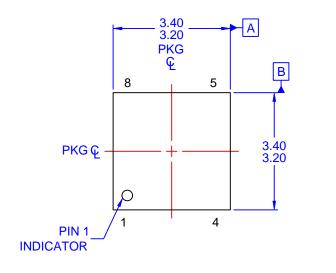


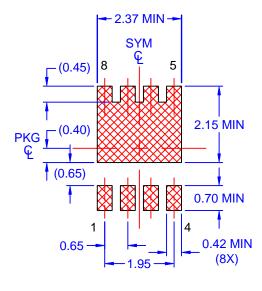
#### ©2015 Fairchild Semiconductor Corporation FDMC8360LET40 Rev.1.0



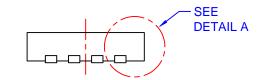


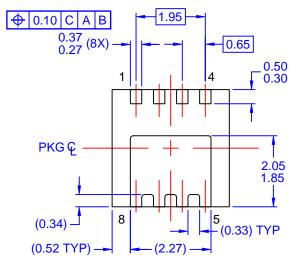


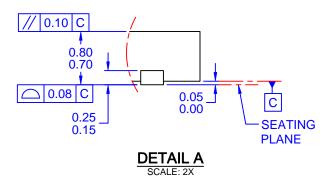












#### NOTES: UNLESS OTHERWISE SPECIFIED

- A) PACKAGE STANDARD REFERENCE: JEDEC MO-240, ISSUE A, VAR. BA, DATED OCTOBER 2002.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS DO NOT INCLUDE BURRS OR MOLD FLASH. MOLD FLASH OR BURRS DOES NOT EXCEED 0.10MM.
- D) DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
- E) DRAWING FILE NAME: PQFN08HREV1

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